P-Channel 30-V (D-S) MOSFET

These miniature surface mount MOSFETs utilize a high cell density trench process to provide low $r_{DS(on)}$ and to ensure minimal power loss and heat dissipation. Typical applications are DC-DC converters and power management in portable and battery-powered products such as computers, printers, PCMCIA cards, cellular and cordless telephones.

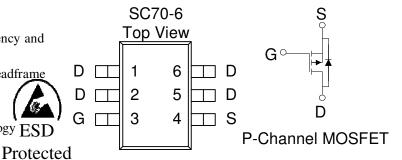
•	Low $r_{DS(on)}$ provides higher efficiency and
	extends battery life

• Low thermal impedance copper leadframe SC70-6 saves board space

Fast switching speed

High performance trench technology ESD

PRODUCT SUMMARY			
V _{DS} (V)	$r_{DS(on)}$ (OHM)	$I_{D}(A)$	
-30	$0.064 @ V_{GS} = -10V$	-4.1	
	$0.096 @ V_{GS} = -4.5V$	-3.3	



ABSOLUTE MAXIMUM RATINGS (T _A = 25 °C UNLESS OTHERWISE NOTED)					
Parameter		Symbol	Maximum	Units	
Drain-Source Voltage			-30	V	
Gate-Source Voltage			±20	V	
Continuous Drain Current ^a	$T_A=25^{\circ}C$] _{T_}	-4.1		
Continuous Drain Current	$T_A=25^{\circ}C$ $T_A=70^{\circ}C$	1D	-3.3	A	
Pulsed Drain Current ^b		I_{DM}	-10		
Continuous Source Current (Diode Conduction) ^a		I_S	±1.4	A	
D	$T_A=25^{\circ}C$	D	1.56	w	
Power Dissipation ^a	$T_A=25^{\circ}C$ $T_A=70^{\circ}C$	r _D	0.81	**	
Operating Junction and Storage Temperature Range		T _J , T _{stg}	-55 to 150	°C	

THERMAL RESISTANCE RATINGS					
Parameter		Symbol	Maximum	Units	
N	$t \leq 5 \sec$	R_{THJA}	80	°C/W	
Maximum Junction-to-Ambient ^a	Steady-State		125		

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Notes

- a. Surface Mounted on 1" x 1" FR4 Board.
- b. Pulse width limited by maximum junction temperature

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SPECIFICATIONS (T _A = 25°C UNLESS OTHERWISE NOTED)							
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Parameter	Symbol	Test Conditions	Min	Тур	Max	Unit	
Static							
Gate-Threshold Voltage	$V_{GS(th)}$	$V_{DS} = V_{GS}, I_D = -250 \text{ uA}$	-1			V	
Gate-Body Leakage	Igss	$V_{DS} = 0 \text{ V}, V_{GS} = \pm 20 \text{ V}$			±10	μA	
Zara Cata Valtaga Prain Current	T .	$V_{DS} = -24 \text{ V}, V_{GS} = 0 \text{ V}$	-		-1		
Zero Gate Voltage Drain Current	I _{DSS}	$V_{DS} = -24 \text{ V}, V_{GS} = 0 \text{ V}, T_J = 55^{\circ}\text{C}$			-10	μA	
On-State Drain Current ^A	I _{D(on)}	$V_{DS} = -5 \text{ V}, V_{GS} = -4.5 \text{ V}$	-5			A	
D i G O D i A	_	$V_{GS} = -10 \text{ V}, I_D = -1 \text{ A}$			64	mΩ	
Drain-Source On-Resistance ^A	r _{DS(on)}	$V_{GS} = -4.5 \text{ V}, I_D = -1 \text{ A}$			96	1112	
Forward Tranconductance ^A	g _{fs}	$V_{DS} = -5 \text{ V}, I_D = -1 \text{ A}$		9		S	
Diode Forward Voltage	V_{SD}	$I_S = -0.46 \text{ A}, V_{GS} = 0 \text{ V}$		-0.65		V	
Dynamic ^b							
Total Gate Charge	Qg	$V_{DS} = -10 \text{ V}, V_{GS} = -4.5 \text{ V},$		4			
Gate-Source Charge	Q_{gs}	$V_{DS} = -10 \text{ V}, V_{GS} = -4.5 \text{ V},$ $I_{D} = -1 \text{ A}$		1		nC	
Gate-Drain Charge	Qgd			2			
Turn-On Delay Time	t _{d(on)}			9			
Rise Time	t _r	$V_{\rm DD} = -10 \text{ V}, I_{\rm L} = -1 \text{ A},$		4] ,,	
Turn-Off Delay Time	t _{d(off)}	$V_{\rm GEN}$ = -4.5 V, $R_{\rm G}$ = 6 Ω		1		ns	
Fall-Time	t_{f}			2			

Notes

- a. Pulse test: PW <= 300us duty cycle <= 2%.
- Guaranteed by design, not subject to production testing.
- c. Repetitive rating, pulse width limited by junction temperature.

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